

To our customers,

Old Company Name in Catalogs and Other Documents

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April 1st, 2010
Renesas Electronics Corporation

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for new design

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3SK319

Silicon N-Channel Dual Gate MOS FET
UHF RF Amplifier

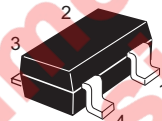
REJ03G0820-0200
(Previous ADE-208-602)
Rev.2.00
Aug.10.2005

Features

- Low noise characteristics;
(NF= 1.4 dB typ. at f= 900 MHz)
- Excellent cross modulation characteristics
- Capable low voltage operation; +B= 5V

Outline

RENESAS Package code: PLSP0004ZA-A
(Package name: MPAK-4)



1. Source
2. Gate1
3. Gate2
4. Drain

Note: Marking is "YB-".

Absolute Maximum Ratings

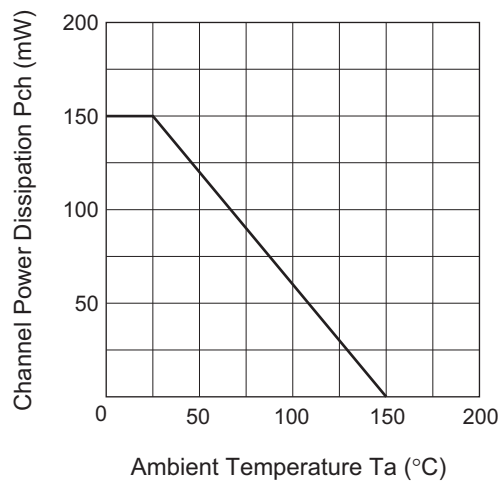
(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DS}	6	V
Gate1 to source voltage	V_{G1S}	±6	V
Gate2 to source voltage	V_{G2S}	±6	V
Drain current	I_D	20	mA
Channel power dissipation	Pch	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

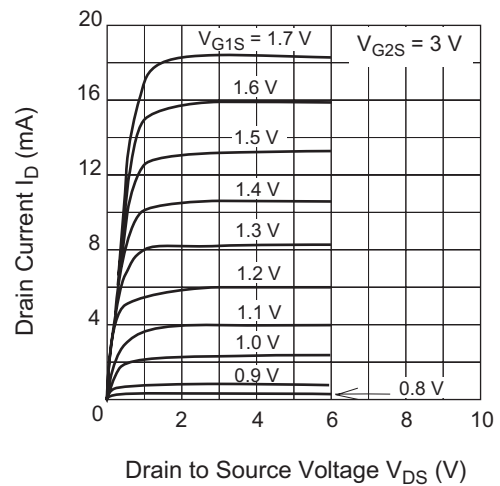
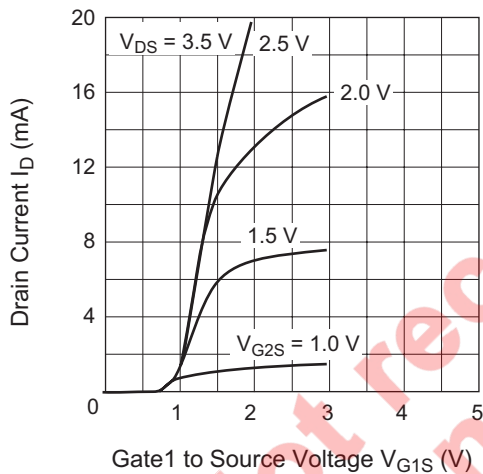
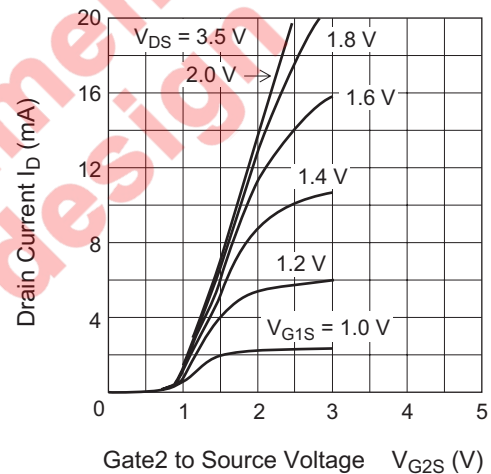
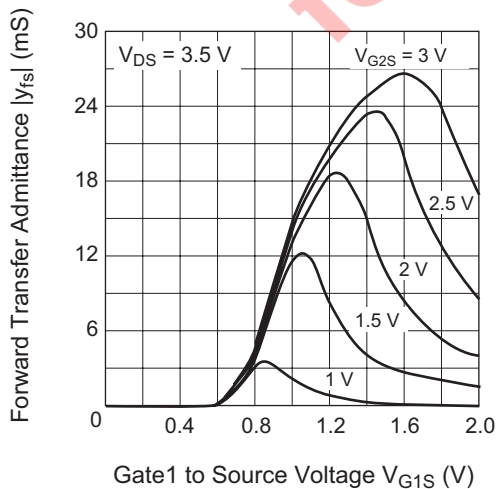
Electrical Characteristics

(Ta = 25°C)

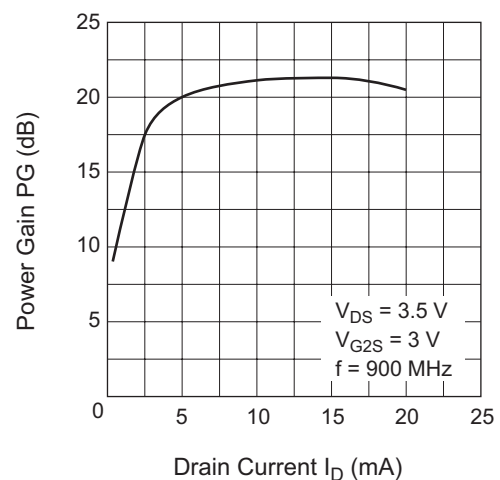
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DS}$	6	—	—	V	$I_D = 200 \mu A$, $V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	$V_{(BR)G1S}$	±6	—	—	V	$I_{G1} = \pm 10 \mu A$, $V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	$V_{(BR)G2S}$	±6	—	—	V	$I_{G2} = \pm 10 \mu A$, $V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff current	I_{G1SS}	—	—	±100	nA	$V_{G1S} = \pm 5 V$, $V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I_{G2SS}	—	—	±100	nA	$V_{G2S} = \pm 5 V$, $V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	$V_{G1S(off)}$	0.5	0.7	1.0	V	$V_{DS} = 5 V$, $V_{G2S} = 3 V$, $I_D = 100 \mu A$
Gate2 to source cutoff voltage	$V_{G2S(off)}$	0.5	0.7	1.0	V	$V_{DS} = 5 V$, $V_{G1S} = 3 V$, $I_D = 100 \mu A$
Drain current	$I_{DS(op)}$	0.5	4	10	mA	$V_{DS} = 3.5 V$, $V_{G1S} = 1.1 V$, $V_{G2S} = 3 V$
Forward transfer admittance	$ y_{fs} $	18	24	32	mS	$V_{DS} = 3.5 V$, $V_{G2S} = 3 V$ $I_D = 10 mA$, $f = 1 kHz$
Input capacitance	Ciss	1.3	1.6	1.9	pF	$V_{DS} = 3.5 V$, $V_{G2S} = 3 V$ $I_D = 10 mA$, $f = 1 MHz$
Output capacitance	CoSS	0.9	1.2	1.5	pF	
Reverse transfer capacitance	CrSS	—	0.019	0.03	pF	
Power gain	PG	18	21	—	dB	$V_{DS} = 3.5 V$, $V_{G2S} = 3 V$
Noise figure	NF	—	1.4	2.2	dB	$I_D = 10 mA$, $f = 900 MHz$

Maximum Channel Power
Dissipation Curve

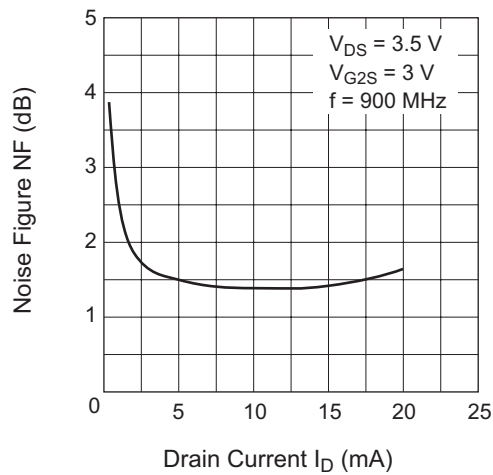
Typical Output Characteristics

Drain Current vs.
Gate1 to Source VoltageDrain Current vs.
Gate2 to Source VoltageForward Transfer Admittance
vs. Gate1 Voltage

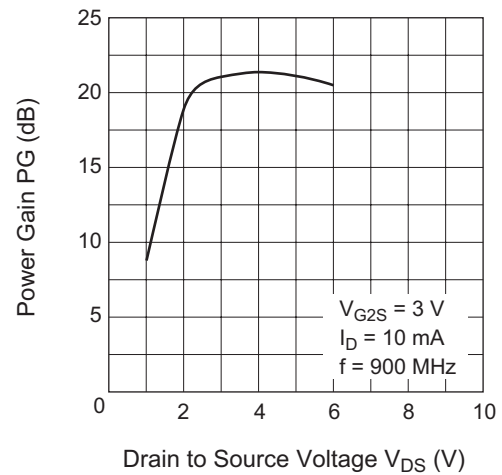
Power Gain vs. Drain Current



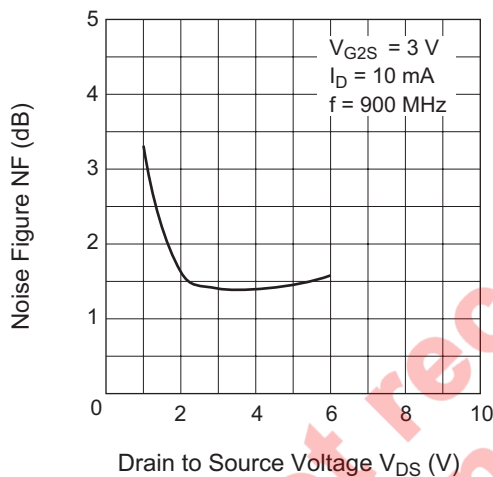
Noise Figure vs. Drain Current



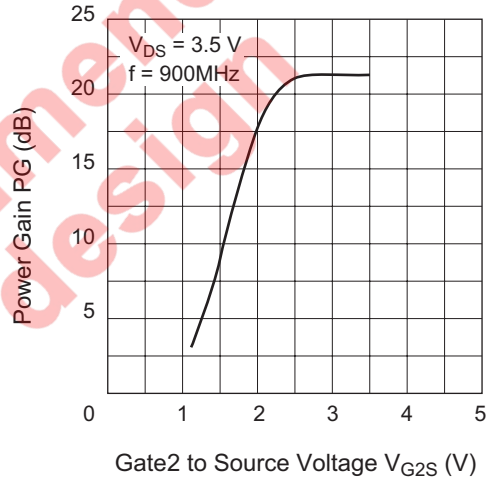
Power Gain vs. Drain to Source Voltage



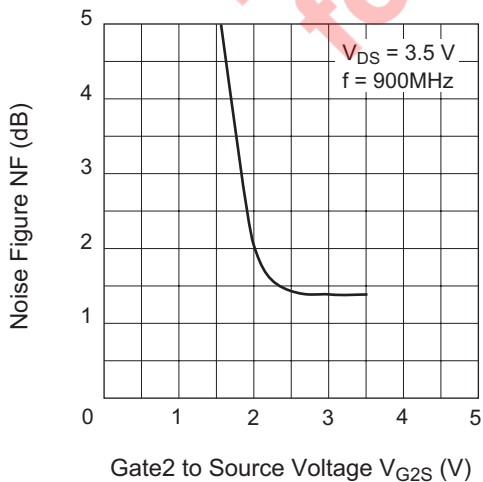
Noise Figure vs. Drain to Source Voltage



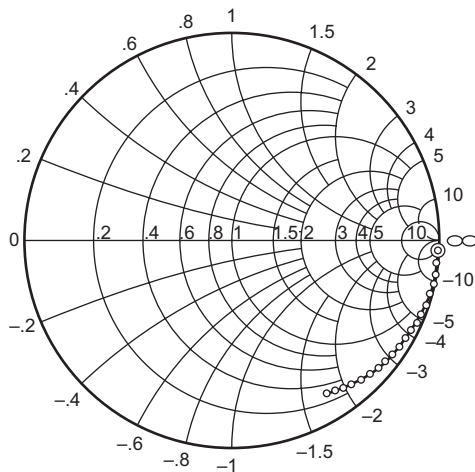
Power Gain vs. Gate2 to Source Voltage



Noise Figure vs. Gate2 to Source Voltage



S11 Parameter vs. Frequency

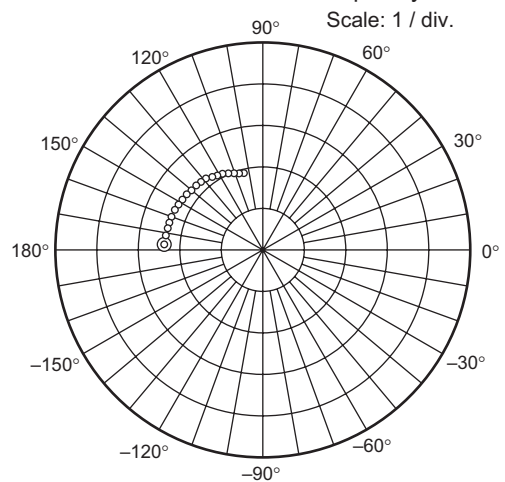


Test Condition : $V_{DS} = 3.5 \text{ V}$, $V_{G2S} = 3 \text{ V}$
 $I_D = 10 \text{ mA}$

50 to 1000 MHz (50 MHz step)



S21 Parameter vs. Frequency

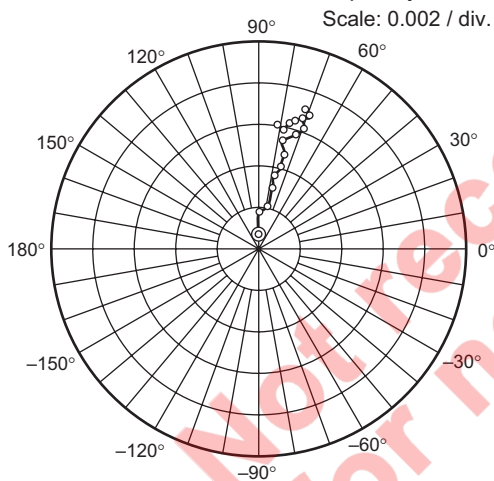


Test Condition : $V_{DS} = 3.5 \text{ V}$, $V_{G2S} = 3 \text{ V}$
 $I_D = 10 \text{ mA}$

50 to 1000 MHz (50 MHz step)



S12 Parameter vs. Frequency

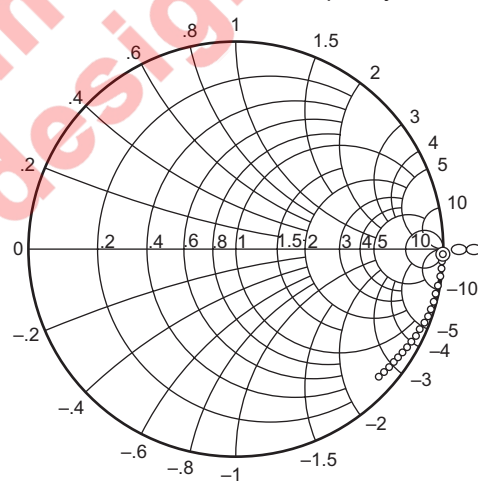


Test Condition : $V_{DS} = 3.5 \text{ V}$, $V_{G2S} = 3 \text{ V}$
 $I_D = 10 \text{ mA}$

50 to 1000 MHz (50 MHz step)



S22 Parameter vs. Frequency



Test Condition : $V_{DS} = 3.5 \text{ V}$, $V_{G2S} = 3 \text{ V}$
 $I_D = 10 \text{ mA}$

50 to 1000 MHz (50 MHz step)

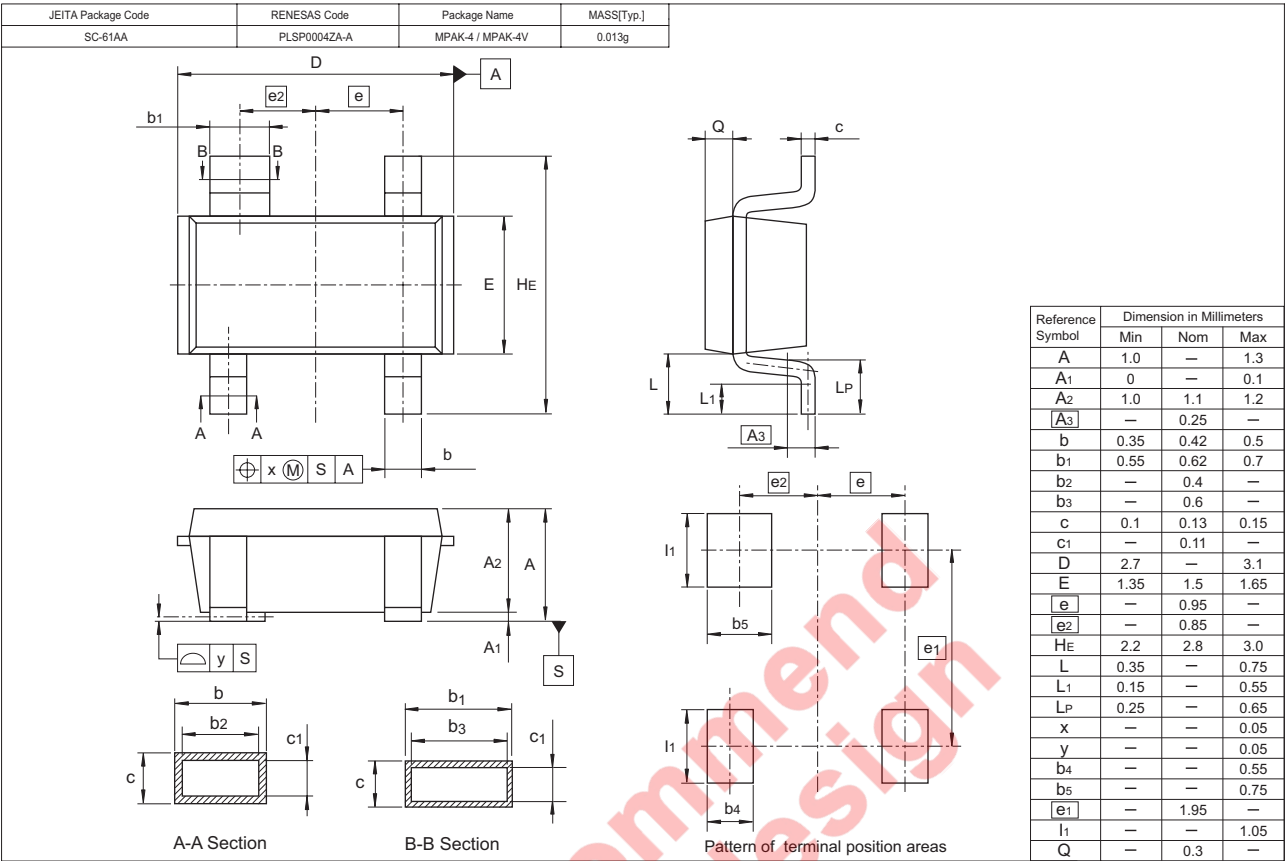


S Parameter

(V_{DS} = 4 V, V_{G2S} = 3 V, I_D = 10 mA, Z_O = 50 Ω)

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
50	1.000	-2.8	2.41	176.3	0.00068	89.1	0.999	-2.2
100	0.998	-5.8	2.41	171.9	0.00176	88.5	0.996	-4.5
150	0.997	-9.1	2.39	167.6	0.00223	80.7	0.996	-6.7
200	0.994	-12.2	2.38	163.7	0.00303	76.6	0.994	-8.7
250	0.994	-15.1	2.37	159.8	0.00365	79.1	0.991	-11.0
300	0.986	-18.5	2.35	155.5	0.00414	75.4	0.988	-13.2
350	0.978	-21.3	2.30	151.4	0.00484	75.0	0.983	-15.3
400	0.972	-24.1	2.28	147.6	0.00533	78.0	0.980	-17.4
450	0.969	-27.0	2.26	143.6	0.00588	71.6	0.976	-19.6
500	0.954	-29.7	2.23	140.0	0.00617	69.5	0.971	-21.7
550	0.955	-32.8	2.19	135.9	0.00666	71.5	0.966	-23.7
600	0.941	-35.7	2.17	132.2	0.00672	70.6	0.960	-25.6
650	0.932	-38.3	2.14	128.6	0.00694	69.0	0.955	-27.8
700	0.924	-41.3	2.09	125.0	0.00709	71.4	0.948	-29.9
750	0.919	-44.1	2.07	121.5	0.00689	69.0	0.942	-31.8
800	0.905	-46.9	2.03	117.9	0.00699	68.9	0.937	-33.8
850	0.896	-49.2	2.00	114.7	0.00644	74.2	0.930	-35.8
900	0.884	-52.4	1.96	110.4	0.00633	75.5	0.923	-37.6
950	0.880	-54.7	1.93	107.1	0.00585	77.8	0.917	-39.8
1000	0.866	-57.7	1.89	103.8	0.00605	82.1	0.910	-41.9

Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
3SK319YB-TL-E	3000	φ 178 mm Reel, 8 mm Emboss Taping

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